

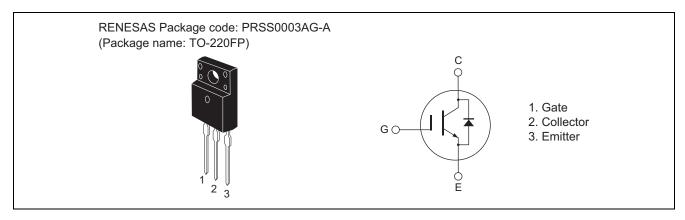
RJH60D1DPP-E0

600V - 10A - IGBT Application: Inverter R07DS0893EJ0100 Rev.1.00 Nov 01, 2012

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.9 \text{ V}$ typ. (at $I_C = 10 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}\text{C}$)
- Built in fast recovery diode (70 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching $t_f=75 \text{ ns typ. (at $V_{CC}=300$ V, $V_{GE}=15$ V, $I_C=10$ A, $Rg=5$ Ω, inductive load)}$

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit	
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V	
Gate to emitter voltage		V _{GES}	±30	V	
Collector current	Tc = 25°C	Ic	20	A	
	Tc = 100°C	Ic	10	A	
Collector peak current		ic(peak) Note1	40	А	
Collector to emitter diode forward current		i _{DF}	10	А	
Collector to emitter diode forward peak current		i _D (peak) Note1	40	А	
Collector dissipation		P _C Note2	30	W	
Junction to case thermal resistance (IGBT)		θj-c Note2	4.1	°C/W	
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	7.2	°C/W	
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to +150	°C	

Notes: 1. PW \leq 10 $\mu s,$ duty cycle \leq 1%

2. Value at Tc = 25°C

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector to emitter breakdown voltage	V _{BR(CES)}	600	_	_	V	$I_C = 10 \mu A, V_{GE} = 0$	
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	_	_	5	μΑ	V _{CE} = 600 V, V _{GE} = 0	
Gate to emitter leak current	I _{GES}		_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{\text{GE(off)}}$	4.0	_	6.0	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	$V_{CE(sat)}$	_	1.9	2.5	V	$I_C = 10 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.6	_	V	$I_C = 20 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	275	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	25	_	pF	$V_{GE} = 0$	
Reveres transfer capacitance	Cres	_	8	_	pF	f = 1 MHz	
Total gate charge	Qg	_	13	_	nC	V _{GE} = 15 V V _{CE} = 300 V I _C = 10 A	
Gate to emitter charge	Qge	_	3	_	nC		
Gate to collector charge	Qgc	_	5	_	nC		
Turn-on delay time	t _{d(on)}	_	30	_	ns	$V_{CC} = 300 \text{ V}$ $V_{GE} = 15 \text{ V}$ $I_{C} = 10 \text{ A}$ $Rg = 5 \Omega$	
Rise time	t _r	_	13	_	ns		
Turn-off delay time	t _{d(off)}	_	42	_	ns		
Fall time	t _f	_	75	_	ns		
Turn-on energy	Eon	_	0.10	_	mJ	(Inductive load)	
Turn-off energy	E _{off}	_	0.13	_	mJ		
Total switching energy	E _{total}	_	0.23	_	mJ		
Short circuit withstand time	t _{sc}	3.0	5.0	_	μS	$V_{GE} \leq 360~V,~V_{GE} = 15~V$	
FRD forward voltage	V _F	_	1.4	1.9	V	I _F = 10 A ^{Note3}	
FRD reverse recovery time	t _{rr}	_	70	_	ns	I _F = 10 A	
FRD reverse recovery charge	Qrr	_	0.11	_	μС	$di_F/dt = 100 A/\mu s$	

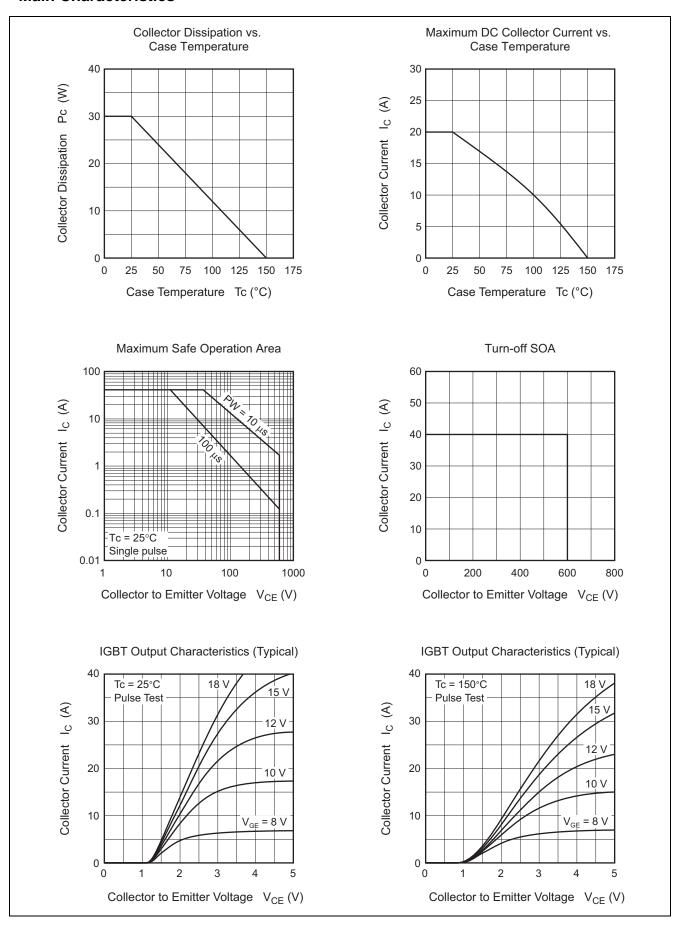
3.5

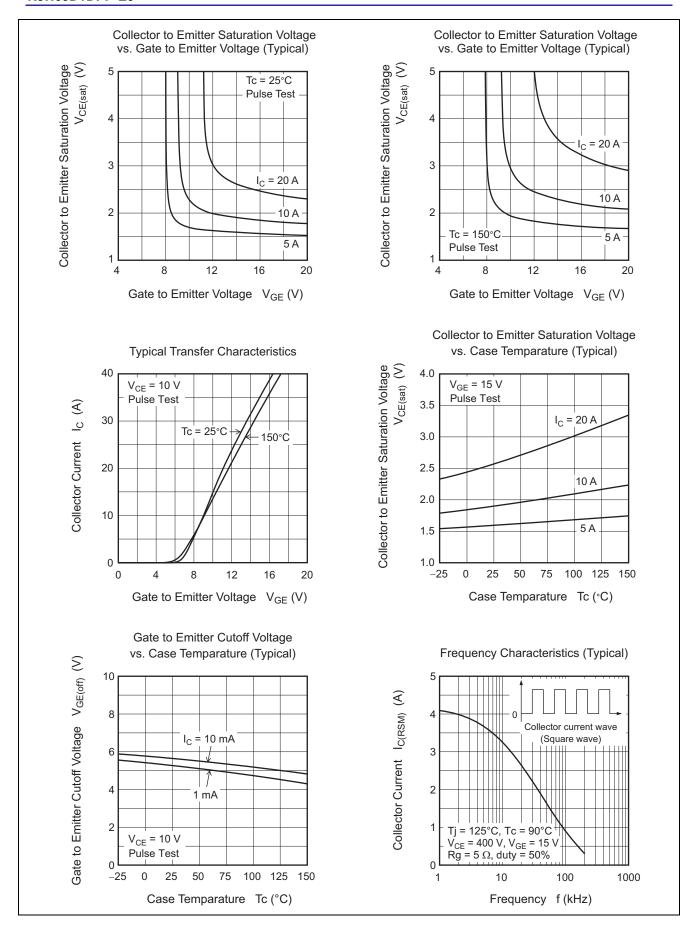
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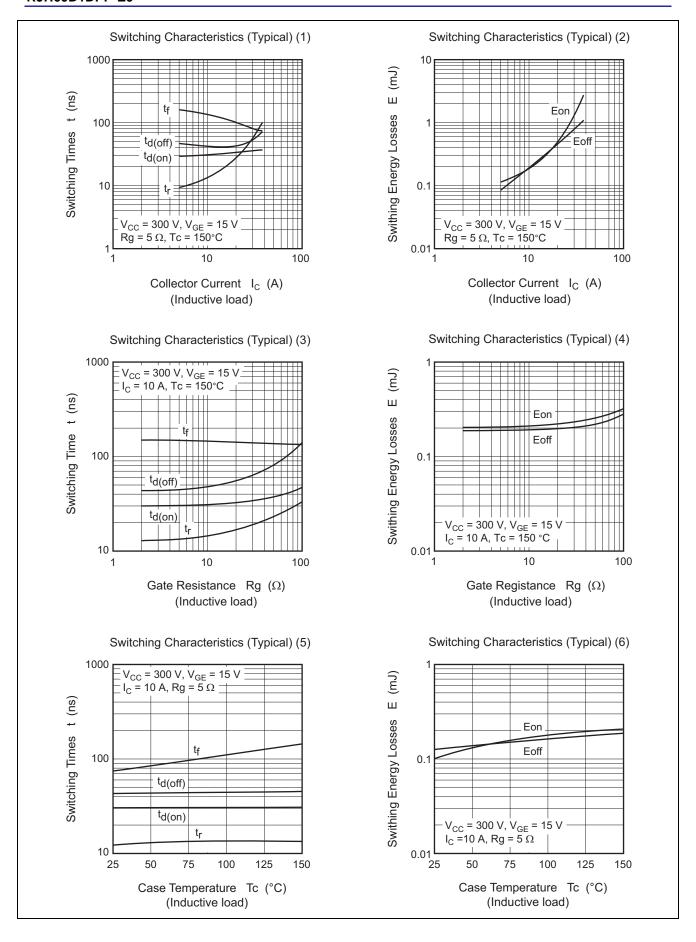
Notes: 3. Pulse test.

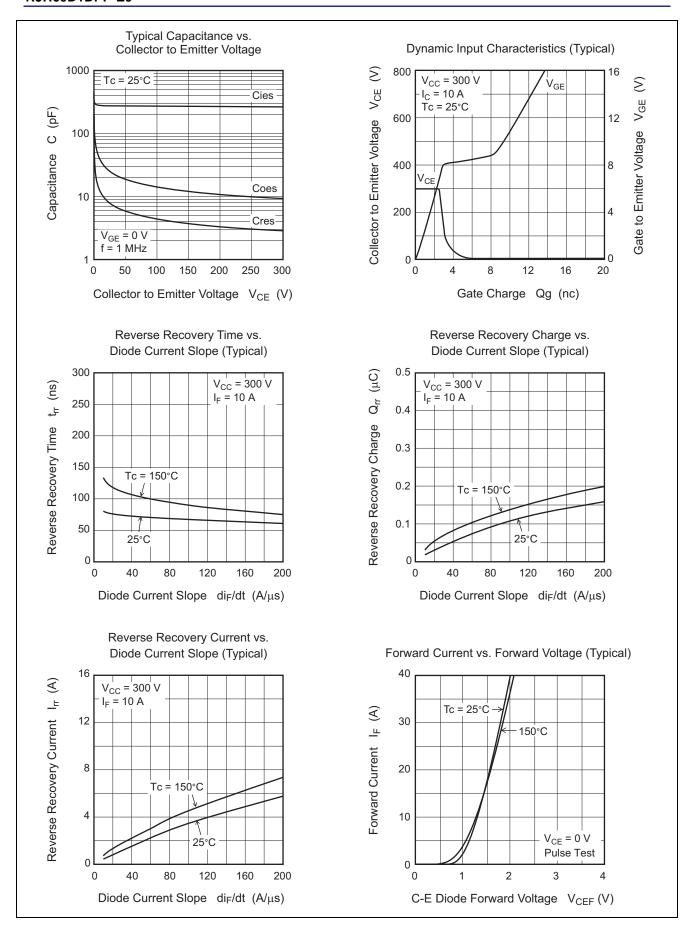
FRD peak reverse recovery current

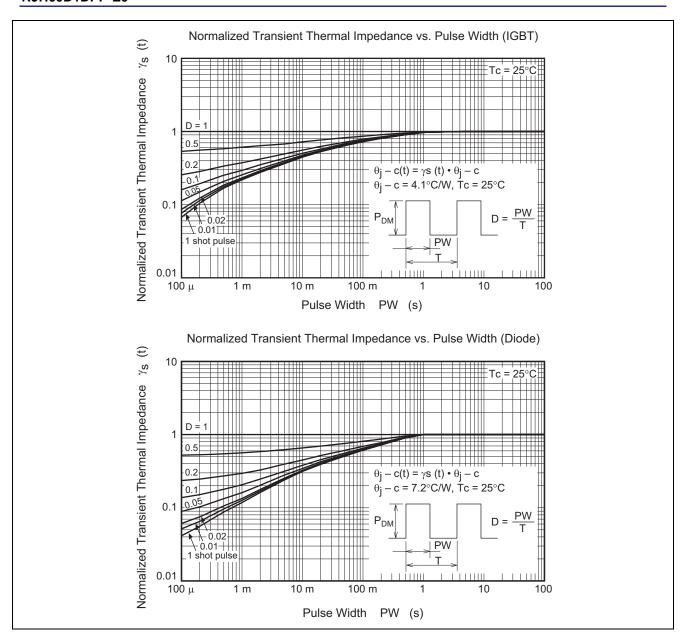
Main Characteristics

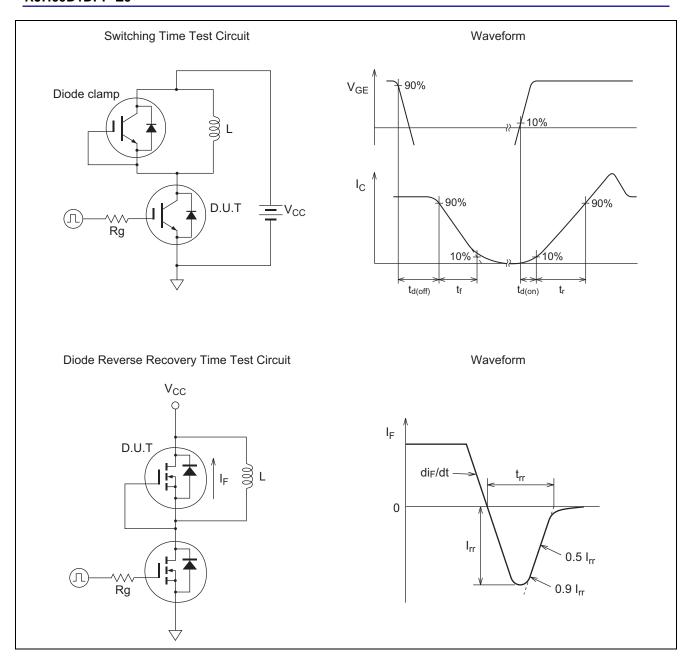




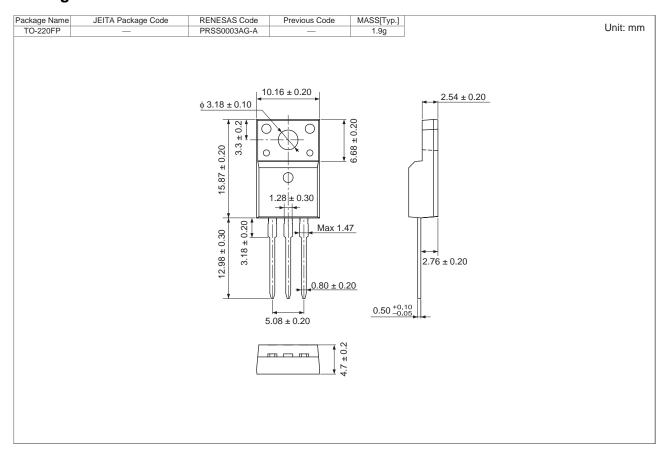








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60D1DPP-E0#T2	1000 pcs	Box (Tube)

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Renesas Electronics America Inc. 2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A. Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd. 7th Floor, Quantum Plaza, No.27 ZhiChunLu Ha Tel: +86-10-8235-1155, Fax: +86-10-8235-7679 nunLu Haidian District, Beijing 100083, P.R.China

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2868-9318, Fax: +852 2869-9022/9044

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

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เกลาเออออ Erectionius เพลาสู่ysta 3นที.bnu. Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd. 11F., Samik Lavied' or Bldg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea Tel: 482-2-588-3737, Fax: 482-2-588-5141

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